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Investigations on the existence of piezoelectric property of a bio-polymer – chitosan and its application in vibration sensors

E. Praveen,^a S. Murugan^b and K. Jayakumar *^a

A variety of physical and chemical properties of bio-polymers like chitosan have been investigated although their inherent behavior, such as piezoelectricity, has not been investigated to date. In this study, an attempt has been made to investigate the presence of non-centrosymmetry in chitosan through X-ray diffraction (XRD) analysis and second harmonic generation (SHG) experiment. Existence of piezoelectricity is established by determining d_{33} coefficient for various pressures. With the help of the above mentioned results, a new application of the bio-polymer chitosan as a piezoelectric element in vibration sensors has been analyzed. To fabricate vibration sensor elements, chitosan was dissolved in various organic acids and its suitability for these applications was studied. Through isolation resistance measurement, the fabricated sensor is found to exhibit very high isolation, which is suitable even in hazardous environments. All the abovementioned investigations reveal the suitability of using chitosan in vibration sensors.

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Introduction

The family of polymers, such as chitin and chitosan, possesses a variety of physical and chemical properties. In nature, chitin is found in the exoskeletons of arthropods and insects, shells of molluscs, pens and beaks of cephalopods, and cell-wall fungi such as Mucoraceae. Commercially, chitin and its derivatives, such as chitosan, are isolated from shells of crab, shrimp, prawn *etc. via* conventional steps such as demineralization, deproteinization, decolouration and deacetylation.¹ Chitosan is the second most generous natural polysaccharide after cellulose on earth. These kind of resources are estimated to be available in ~100 billion tons in nature.² Contrary to chitin, both amino and hydroxyl groups of chitosan can be selectively modified for versatile applications. Chitosan exhibits several properties such as biocompatibility, biodegradability, non-toxicity, and easily film formation ability that are advantageous for industrial and biomedical applications such as water treatment,³ dye removal,⁴ tissue engineering,⁵ wound healing and dressing,^{6,7} and drug delivery.⁸ Silva *et al.* have reported that the addition of chitosan to collagen polymer⁹ exhibits a considerable increment in the piezoelectric strain constant (d_{14}). Recently, ferroelectric materials such as ZnO and BaTiO₃ exhibiting piezoelectric property were embedded in chitosan polymer and used for the detection of mechanical excitation, where the piezoelectric nature of ZnO

and BaTiO₃ was focused on and the electret was tested for mechanical sensing applications.^{10,11} In the present study, an attempt has been made to investigate the existence of non-centrosymmetry in chitosan through second harmonic generation (SHG) and that of piezoelectric property by measuring the piezoelectric strain coefficient (d_{33}). After the analysis of SHG and d_{33} data, isolation measurements of the chitosan samples are conducted by 80 Hz mechanical excitation. Sensitivity and selectivity of chitosan dissolved in various organic acids were studied and have been reported.

Experimental techniques

Chitosan used in the preparation of sensor elements was of analytical grade and procured from Pelican Biotech and Chemical Labs, India, and organic acids (such as formic, acetic, adipic, and succinic acids) were procured from CDH, India, without further purification for the investigations. The degree of deacetylation (DDA) of chitosan was 91.2%. The flakes of chitosan were fine grained with formic acid in an agate mortar that was air dried for few hours, and pellets of thickness 1.3 mm were prepared using the manual hydraulic pressure unit for the piezoelectric strain coefficient (d_{33}) measurement. Since film-casting method is a very simple and cost-effective technique for making freestanding films of chitosan, casting technique has been adopted for the preparation of samples. Thin films of chitosan were prepared by dissolving chitosan in formic, acetic, adipic, and succinic acids in separate flasks with an optimum concentration of 1.5% and stirred using a mechanical stirrer. The percentage of acid used for dissolving chitosan was

^aNanostructure Lab, Department of Physics, The Gandhigram Rural Institute-Deemed University, Gandhigram-624 302, Tamilnadu, India. E-mail: kjkumar_gri@rediffmail.com

^bIPRC-ISRO, Mahendragiri – 627 754, Tamilnadu, India



Table 1 IR active modes of chitosan and formate of chitosan and their respective vibrations in cm^{-1a}

S. No.	Wavenumber ^{13,18–20} ($\bar{\lambda}$)	Chitosan		Formate of chitosan	
		Observed $\bar{\lambda}$	Assignment	Observed $\bar{\lambda}$	Assignment
1	3428	3422	$\nu(\text{OH})$	3422	$\nu(\text{OH})$
2	3196	3340	$\nu(\text{NH})$	3354	$\nu(\text{NH}) + \nu(\text{HCOO})$
3	2919	2924	$\nu(\text{CH}_3)$	2926	$\nu(\text{CH}_3)$
4	2875	2872	$\nu(\text{CH}_2)$	2874	$\nu(\text{CH}_2)$
5		2854		2854	
6	1658	1654	$\nu(\text{CO})$	1600	$\nu(\text{CO}) + \delta(\text{NH}) + \delta(\text{NH}_2) + \nu(\text{HCOO})$
7	1627	1638	$\delta(\text{NH})$ chitin		
8	1565	1578	$\delta(\text{NH}_2)$		
9	1422	1424	$\delta(\text{CH}) + \delta(\text{OH})$	1380	$\delta(\text{CH}) + \delta(\text{OH}) + \delta(\text{CH}_3)$
10	1417	1410	$\delta(\text{CH}_3) + \delta(\text{CH})$ chitin		
11	1156	1150	$\delta(\text{CH}) + \delta(\text{OH})$	1154	$\delta(\text{CH}) + \delta(\text{OH})$
12	1075	1070		1076	
13	1033	1026	$\nu(\phi) + \delta(\text{CH})$	1034	$\nu(\phi) + \delta(\text{CH})$
14	896	906	$\nu(\phi) + \rho(\text{CH}_2)$	902	$\nu(\phi) + \rho(\text{CH}_2)$
15		830		854	
16	595	594	$\delta(\phi)$	592	$\delta(\phi)$
17	465	474	$\delta(\text{COC})$ chitin		

^a ν – stretching, δ – in-plane bending and ρ – rocking vibrations; ϕ – pyranoid ring.

signals. Hence, chitosan flakes were verified for SHG with excitation of 1064 nm using a Nd:YAG laser. The laser power used was typically less than 100 mW to avoid local heating of the sample. The generated second harmonic signals were compared with those of potassium diphosphate (KDP) crystal as a reference. Intensity of SHG signals generated for chitosan and formate of chitosan were 90% and 86% with respect to the KDP crystal, respectively. Although there is a small reduction in the SHG signal of chitosan dissolved in formic acid, the non-centrosymmetry is not altered. Hence, the existence of non-centrosymmetry in chitosan is well established, which will provide a new way for the fabrication of devices such as

piezoelectric pressure sensors. SHG signals of chitosan and formate of chitosan are depicted in Fig. 3a with the comparison of the Nd:YAG source and KDP reference. Normalized SHG intensities and SHG intensity at 532 nm for chitosan dissolved in formic, acetic, succinic, and adipic acids are shown in Fig. 3b and c, respectively. Fig. 3b and c show that the intensity of the SHG signal is more pronounced 532 nm for chitosan dissolved in formic acid than that for chitosan dissolved in other organic acids, indicating the manifestation of the non-centrosymmetric nature.

Piezoelectric coefficient (d_{33}) of chitosan. Piezoelectric strain coefficient of formate of chitosan is measured for various

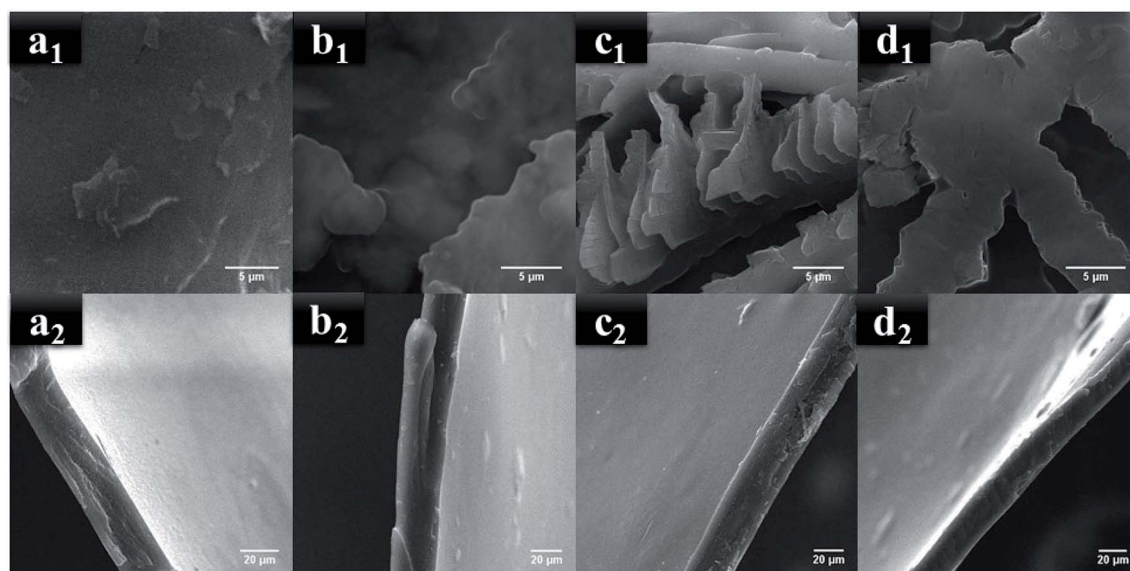


Fig. 2 Scanning electron images with top and cross sectional views of chitosan dissolved in (a) formic (b) acetic (c) succinic and (d) adipic acids.



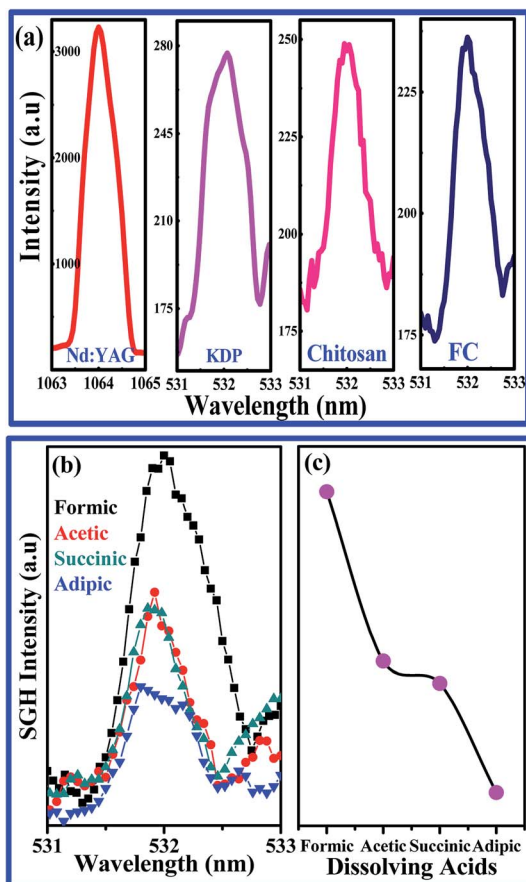


Fig. 3 (a) SHG signals of Nd:YAG source, KDP, chitosan and formate of chitosan (b) normalized SHG intensities and (c) SHG intensity at 532 nm of chitosan dissolved with formic, acetic, succinic and adipic acids.

pressures as a function of sintering temperature. Since the measured d_{33} values are oscillatory, the most stable values are averaged and are presented in Fig. 4. From the measurement of the d_{33} coefficient, it is observed that up to 330 K, the sample is stable and has a maximum d_{33} coefficient of 18.4 pC N^{-1} for a load of 5 tons. Further increase in temperature leads to decrease in the d_{33} coefficient, which may be due to the disappearance of non-centrosymmetry of chitosan. The measured d_{33} coefficients with the experimental errors are given in Table 2.

Application: chitosan as a vibration sensor

The existence of non-centrosymmetry and hence the piezoelectricity in the chitosan are confirmed through the above-mentioned experiments: SHG and d_{33} measurements. Although it exhibited non-centro symmetry and hence the piezoelectric property, it was tested for suitability in applications such as in vibration sensors. The chitosan samples were also tested for the isolation measurement and mechanical excitation by an 80 Hz shaker, as given in Fig. 5a.

Electrical response of chitosan: isolation resistance. If the prepared sensor material is used in a precarious setting, it is very essential to establish an isolation between the sensor and the test material ground. The maximum isolation required for

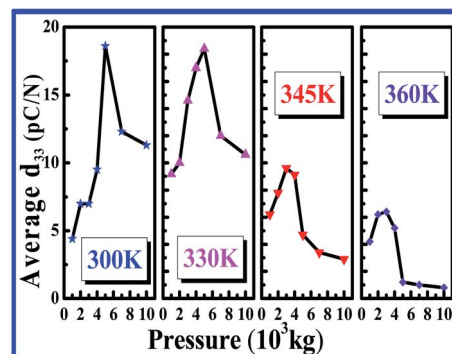


Fig. 4 d_{33} coefficient of formate of chitosan for various pressures and sintering temperatures.

safety measurement is only $\sim 100 \text{ V}_{\text{dc}}$. Therefore, if the samples are capable of more than the required isolation, then they can be used as a sensor material for mechanical sensing. The chitosan films (formate, acetate, succinate, and adipate) were electrically characterized using the isolation meter at 50, 100, 250, 500, and 1000 V_{dc} . The isolation resistance is given in Table 3. It is observed that our samples have very high isolation resistance (~ 0.4 to more than $1 \text{ G}\Omega$) as compared to those obtained in our earlier studies,^{10,11} which confirms the suitability of formate of chitosan for the fabrication of mechanical sensor elements.

Mechanical response of chitosan: detection of 80 Hz mechanical oscillations. Thin films of chitosan are mounted between the isolation stud and the stainless steel electrode by spot welding technique. The whole setup now acts as a mechanical sensor when it is excited. When mechanical excitation is applied on the electrode disks, it leads to compression and decompression of the chitosan films, which generates charge output based on the magnitude of mechanical excitation. An electrical connection is made to the microdot cable of RG188 standard, and it is attached to the signal conditioner of PCB 481 series for high frequency data acquisition. The top and bottom electrodes are attached with a lead wire for the measurement of charge. This total assembly and the top and bottom disks are isolated from each other by PTFE isolation tape. Hence, the erroneous output from the sensor

Table 2 d_{33} coefficient of pellets of chitosan of 1.3 mm thickness for various temperatures and applied pressures

Pressure ($10^3 \text{ kg per } 42.25 \text{ mm}^2$)	d_{33} coefficient (pC N^{-1})			
	Temperature (K)			
	300	330	345	360
1	4.4 ± 0.4	9.2 ± 0.2	6.2 ± 0.2	4.2 ± 0.2
2	7.0 ± 0.3	10.0 ± 0.2	7.8 ± 0.1	6.2 ± 0.2
3	7.0 ± 0.3	14.6 ± 0.1	9.6 ± 0.1	6.4 ± 0.1
4	9.5 ± 0.2	17.0 ± 0.1	9.1 ± 0.1	5.2 ± 0.2
5	18.6 ± 0.1	18.4 ± 0.1	4.7 ± 0.2	1.2 ± 0.8
7	12.3 ± 0.1	12.0 ± 0.1	3.4 ± 0.3	1.0 ± 0.9
10	11.3 ± 0.2	10.6 ± 0.1	2.9 ± 0.2	0.8 ± 1.1



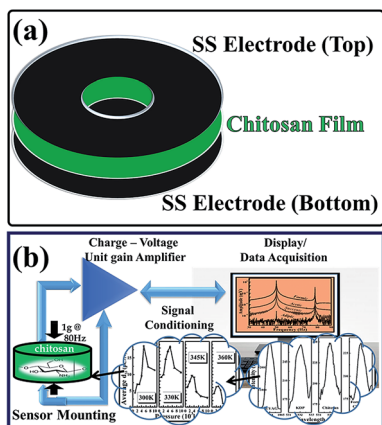


Fig. 5 (a) Chitosan film with stainless steel (SS) electrode plate. (b) Schematic of mechanical excitation measurement and data acquisition.

Table 3 Isolation resistance of thin films of formate, acetate, succinate and adipate of chitosan

S. No.	Sample legend	Isolation measurement				
		50 V _{dc}	100 V _{dc}	250 V _{dc}	500 V _{dc}	1000 V _{dc}
1	Formic	>1 GΩ	>1 GΩ	401 MΩ	516 MΩ	500 MΩ
2	Acetic	>1 GΩ	>1 GΩ	>1 GΩ	>1 GΩ	>1 GΩ
3	Succinic	>1 GΩ	>1 GΩ	>1 GΩ	>1 GΩ	>1 GΩ
4	Adipic	>1 GΩ	>1 GΩ	>1 GΩ	>1 GΩ	>1 GΩ

system is eliminated. The schematic of the measurement of mechanical excitation and data acquisition is depicted in Fig. 5b, and with this arrangement, the fabricated sensor films

are excited mechanically by the generation of 80 Hz mechanical oscillations at 1 gravitational acceleration (g) level. Hence, the charge developed in the fabricated chitosan film corresponds to $1g$, which is almost equivalent to the sensitivity of the sensor element. To confirm the applicability and the realization of chitosan as a sensor, thin films of chitosan are mounted parallel with the commercially available Endeveco-make sensor. When the mechanical excitation of 80 Hz at $1g$ level is applied, the output of the sensor is fed through a Kiestler-make charge-voltage amplifier with unit gain to the signal conditioner. The acquired output is analyzed by the fast Fourier transform (FFT) algorithm to study the frequency components present in the spectrum. Due to the presence of charge leakage in electronic components and other elements such as power line, the output signal experiences noise at 50 Hz. Hence, the output spectrum consists of both 50 Hz and 80 Hz components. FFT spectra of chitosan-based sensors for various acids are shown in Fig. 6a. While fabricating the sensor, it is very essential to eliminate noise from the output, and the power line leakage at 50 Hz may be removed by making a filter circuit, as reported by Wang *et al.*²¹ If the filter circuit is used for the removal of noise from the output spectrum, it may lead to the loss of sensitivity of the sensor and also letdown in detecting mechanical excitation. As an alternative to the abovementioned filter circuit, the sensor could be designed with a hermetical shield, as reported in literature.^{10,11,22}

Sensitivity of chitosan dissolved in organic acids. The output signals obtained from the mechanically excited thin films of chitosan dissolved in organic acids and the commercial sensor are out of phase in amplitude. The output of the chitosan based sensor is shown in Fig. 6b and the phase shifts are compared with those of the commercial sensor output, which is depicted in Fig. 6c. While studying the effect of dissolution of chitosan

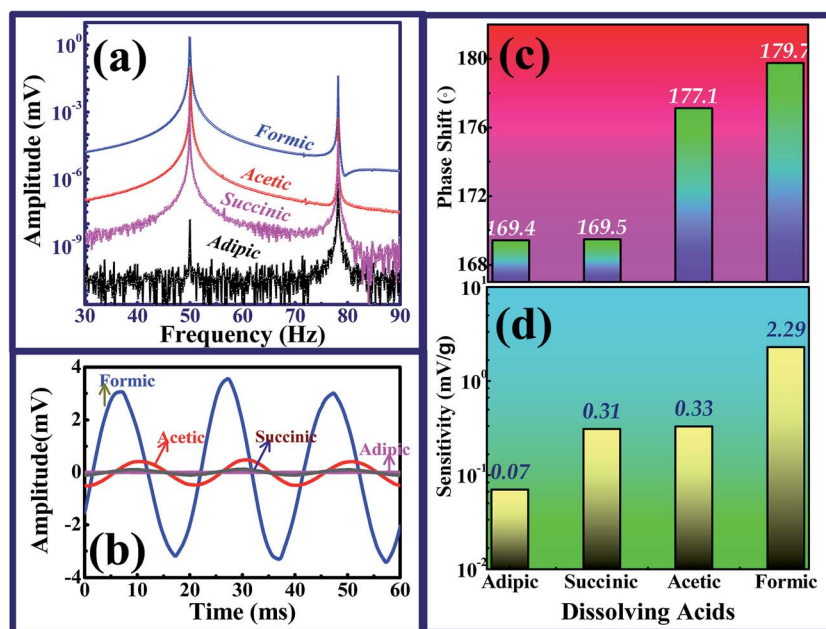


Fig. 6 (a) FFT spectra, (b) output amplitude, (c) phase shift and (d) sensitivity of chitosan based sensor.



on these acids, the sensitivity of formate of chitosan is quite high. Hence, formic acid is endorsed to be the most appropriate acid for sensor fabrication. The sensitivity of various dissolving acids of chitosan is depicted in Fig. 6d.

Conclusion

In the present study, an attempt was made to investigate the existence of non-centrosymmetry of a biopolymer, namely chitosan, through XRD analysis and second harmonic generation experiments. From the SHG experiment, the frequency splitting was observed at 532 nm with the 1064 nm Nd:YAG source, which confirmed the non-centrosymmetry nature of the chitosan samples due to which the chitosan exhibited piezoelectric property. Temperature-dependent d_{33} coefficients for various pressures confirmed the existence of piezoelectricity. Based on the abovementioned results, chitosan was dissolved in various organic acids such as formic, acetic, succinic, and adipic, and the suitability of chitosan film for vibration sensors was studied. Compared with other acids, films prepared by dissolving chitosan in formic acid provided good sensitivity for the sensor. From the isolation resistance measurement, the fabricated sensor films were established to have a very high isolation (~ 0.4 to more than $1 \text{ G}\Omega$) suitable for precarious condition, whereas the explosive environment need isolation only up to $100 \text{ M}\Omega$. However, the excitation vibration is 80 Hz at 1 g , and the output signals are developed with a noise at 50 Hz due to power line leakage. However, the fabrication of the sensor causes a leakage that may be removed by hermetic shielding. All the abovementioned investigations reveal the suitability of chitosan films in vibration sensors.

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